TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

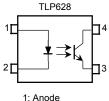
TLP628,TLP628-2,TLP628-4

Programmable Controllers DC-Output Module **Telecommunication**

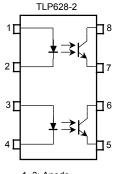
The TOSHIBA TLP628, -2, and -4 consists of a gallium arsenide infrared emitting diode optically coupled to a phototransistor which has a 350V high voltage of collector-emitter breakdown voltage. The TLP628-2 offers two isolated channels in a eight lead plastic DIP package, while the TLP628-4 provide four isolated channels per package.

- Collector-emitter voltage: 350 V (min.)
- Current transfer ratio: 50% (min.)
- Isolation voltage: 5000Vrms (min.)
- UL recognized: UL1577, file No. E67349
- BSI approved: BS EN60065:2002, certificate no.7426 BS EN60950-1:2002, certificate no.7427

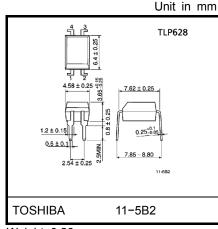
Pin Configurations (top view)



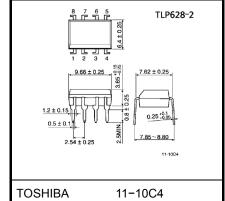
- 2. Cathode 3. Emitter
- 4: Collector



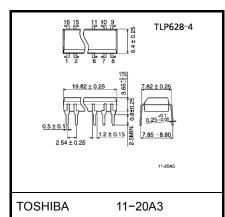
- 2, 4: Cathode
- 5. 7: Emitter
- 6, 8: Collector



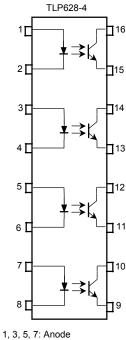
Weight: 0.26g



Weight: 0.54g



Weight: 1.1g



2, 4, 6, 8: Cathode

9, 11, 13, 15: Emitter

10, 12, 14, 16: Collector



Absolute Maximum Ratings (Ta = 25°C)

Characteristic			Ra		
		Symbol	TLP628	TLP628-2 TLP628-4	Unit
	Forward current	l _F	60	50	mA
	Forward current derating	ΔI _F / °C	-0.7 (Ta ≥ 39°C)	–0.5 (Ta ≥ 25°C)	mA / °C
LED	Pulse forward current	I _{FP}	1 (100µs pulse, 100pps)		Α
	Reverse voltage	V _R		V	
	Junction temperature	Tj	12	°C	
	Collector-emitter voltage	V _{CEO}	35	V	
	Emitter-collector voltage	V _{ECO}	-	V	
tor	Collector current	IC	50		mA
Detector	Collector power dissipation (1 circuit)	PC	150	100	mW
	Collector power dissipation derating (Ta ≥ 25°C, 1 circuit)	ΔP _C / °C	-1.5	-1.0	mW / °C
	Junction temperature	Tj	12	°C	
Sto	age temperature range	T _{stg}	−55~125		°C
Operating temperature range		T _{opr}	−55~100		°C
Lead soldering temperature		T _{sol}	260 (10s)		°C
Total package power dissipation (1 circuit)		PT	200 150		mW
Total package power dissipation derating (Ta ≥ 25°C, 1 circuit)		ΔP _T / °C	-2.0 -1.5		mW / °C
Isolation voltage		BVS	5000 (AC, 1min., R.H. ≤ 60%) (Note 1)		Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1) Device considered a two terminal device: LED side pins shorted together and detector side pins shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V _{CC}	_	_	200	V
Forward current	lF	_	16	25	mA
Collector current	IC	_	_	10	mA
Operating temperature	T _{opr}	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.



Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
	Forward voltage	V _F	I _F = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	I _R	V _R = 5 V	_	_	10	μA
	Capacitance	C _T	V = 0, f = 1 MHz	_	30	_	pF
Detector	Collector–emitter breakdown voltage	V _(BR) CEO	I _C = 0.1 mA	350	_	-	V
	Emitter-collector breakdown voltage	V _(BR) ECO	I _E = 0.1 mA	7	_	-	V
	Collector dark current	I _{CEO}	V _{CE} = 300 V	_	10	200	nA
	Collector dark current		V _{CE} = 300 V, Ta = 85°C	_	_	50	μΑ
	Capacitance collector to emitter	C _{CE}	V = 0, f = 1 MHz	_	10	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Current transfer ratio	I _C / I _F	I _F = 5 mA, V _{CE} = 5 V Rank GB	50	_	600	- %
			100	_	600	
Saturated CTR	I _C / I _{F (sat)}	IF = 1 mA, V _{CE} = 0.4 V Rank GB	_	60	1	- %
			30	_	1	
Collector-emitter saturation voltage	VCE (sat)	I _C = 2.4 mA, I _F = 8 mA	_	_	0.4	
		I _C = 0.2 mA, I _F = 1 mA Rank GB	_	0.2	_	V
			_	_	0.4	

Isolation Characteristics (Ta = 25°C)

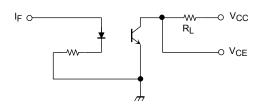
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance input to output	Cs	V _S = 0, f = 1 MHz	_	8.0	_	pF
Isolation resistance	R _S	V _S = 500 V R.H. ≤ 60%	5×10 ¹⁰	10 ¹⁴	-	Ω
Isolation voltage	BVS	AC, 1 minute	5000	_	_	- V _{rms}
		AC, 1 second, in oil	_	10000	-	
		DC, 1 minute, in oil	_	10000	_	V_{dc}

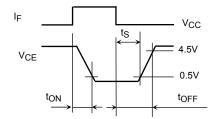


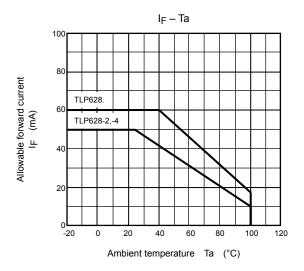
Switching Characteristics (Ta = 25°C)

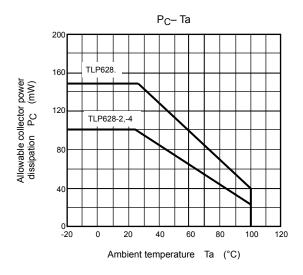
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Rise time	t _r		_	2	_	
Fall time	t _f	V _{CC} = 10 V, I _C = 2 mA	_	3	_	116
Turn-on time	t _{on}	AR _L = 100Ω	_	3	_	μs
Turn-off time	t _{off}		_	3	_	
Turn-on time	ton	R_L = 1.9 kΩ (Fig.1) V_{CC} = 5 V, I_F = 16 mA	_	3	_	
Storage time	ts		_	40	_	μs
Turn-off time	tOFF		_	90	_	

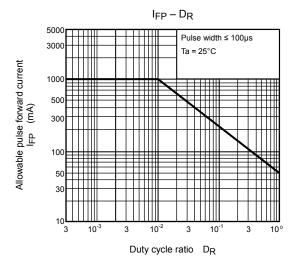
Fig. 1 Switching time test circuit

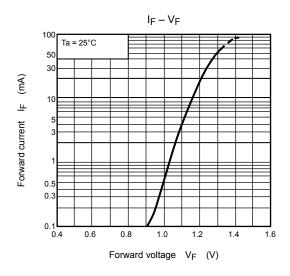


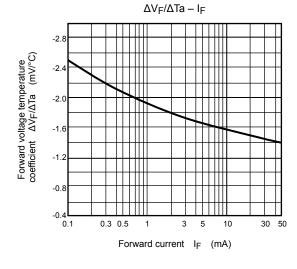


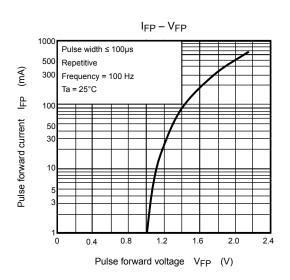




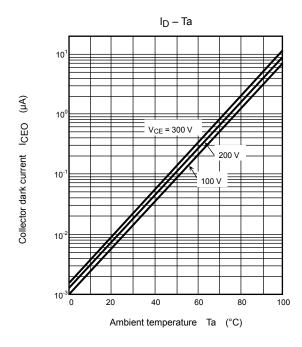


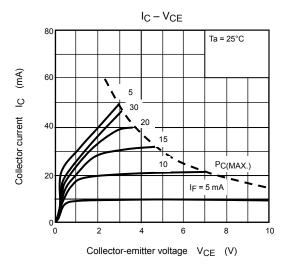


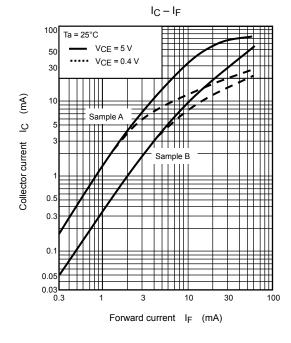


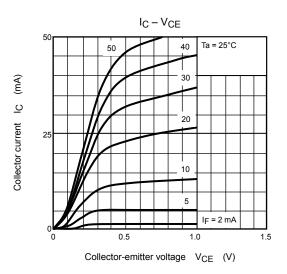


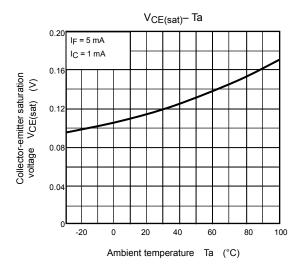
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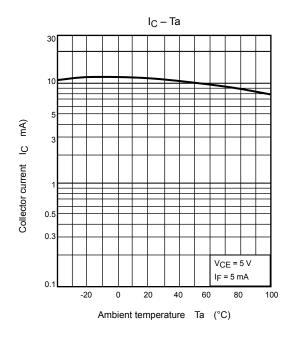


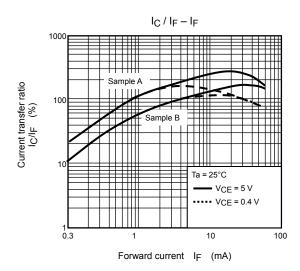


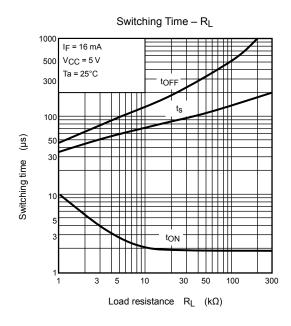












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